⧫The devices are manufactured in epitaxial-base planar technology and are suitable for audio, power linear and switching applications.

⧫General purpose
⧫Audio Amplifier

⧫Low collector-emitter saturation voltage
⧫Complementary to TIP2955

Parameter	Symbol	Value	Unit
Collector-base voltage	BV_{CBO}	100	V
Collector-emitter voltage	BV_{CEO}	60	V
Emitter-base voltage	BV_{EBO}	7	V
Collector current	I_C	15	A
Base current	I_B	7	A
Power dissipation	P_D	90	W
Junction temperature	T_j	150	
Storage temperature	T_{stg}	-40 150	
Thermal resistance junction to case	R	1.55	